

**TO - 92 BIPOLAR TRANSISTORS  
TRANSISTOR(PNP)**

**FEATURES**

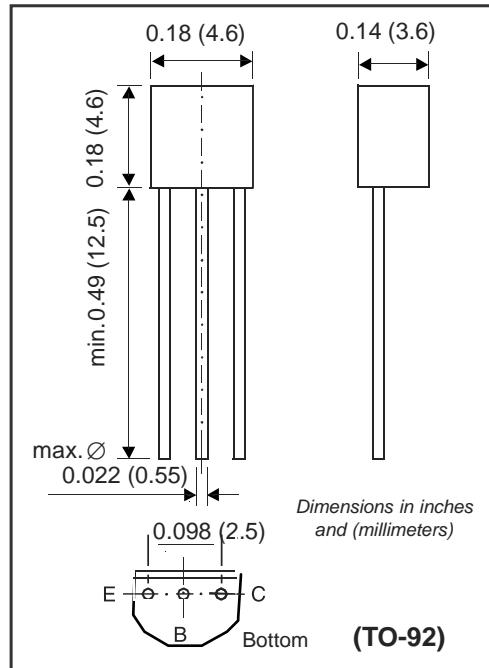
- \* Power dissipation  
P<sub>CM</sub>: 0.6 W(T<sub>amb</sub>=25°C)
- \* Collector current  
I<sub>CM</sub>: -0.6 A
- \* Collector-base voltage  
V<sub>(BR)CBO</sub>: -40 V
- \* Operating and storage junction temperature range  
T<sub>J</sub>, T<sub>stg</sub>: -55°C to +150°C

**MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-O rate flame retardant
- \* Lead: MIL-STD-202E method 208C guaranteed
- \* Mounting position: Any
- \* Weight: 0.008 gram

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.



**MAXIMUM RATINGS** ( @ T<sub>A</sub> = 25°C unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS
Max. Steady State Power Dissipation <sup>(1)</sup> @T <sub>A</sub> =25°C Derate above 25°C	P <sub>D</sub>	600	mW
Max. Operating Temperature Range	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

**ELECTRICAL CHARACTERISTICS** ( @ T<sub>A</sub> = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	-	-	417	°C/W

Notes :1. Alumina=0.4\*0.3\*0.024in,99.5% alumina  
2. "Fully ROHS Compliant", "100% Sn plating (Pb-free)".

**ELECTRICAL CHARACTERISTICS** (@TA=25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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**OFF CHARACTERISTICS**

Collector-Emitter Breakdown Voltage(1) ( $I_C = -1.0 \text{ mAdc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	-40	-	Vdc
Collector-Base Breakdown Voltage ( $I_C = -0.1 \text{ mAdc}$ , $I_E = 0$ )	$V_{(BR)CBO}$	-40	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = -0.1 \text{ mAdc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	-5.0	-	Vdc
Base Cutoff Current ( $V_{CE} = -35 \text{ Vdc}$ , $V_{BE(off)} = -0.4 \text{ Vdc}$ )	$I_{BEV}$	-	-0.1	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = -35 \text{ Vdc}$ , $V_{EB} = -0.4 \text{ Vdc}$ )	$I_{CEX}$	-	-0.1	$\mu\text{Adc}$

**ON CHARACTERISTICS (1)**

DC Current Gain ( $I_C = -0.1 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ ) ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ ) ( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ ) ( $I_C = -150 \text{ mAdc}$ , $V_{CE} = -2.0 \text{ Vdc}$ ) ( $I_C = -500 \text{ mAdc}$ , $V_{CE} = -2.0 \text{ Vdc}$ )	hFE	30	-	-
		60	-	
		100	-	
		100	300	
		20	-	
Collector-Emitter Saturation Voltage (1) ( $I_C = -150 \text{ mAdc}$ , $I_B = -15 \text{ mAdc}$ ) ( $I_C = -500 \text{ mAdc}$ , $I_B = -50 \text{ mAdc}$ )	$V_{CE(sat)}$	-	-0.4	Vdc
		-	-0.75	
Base-Emitter Saturation Voltage (1) ( $I_C = -150 \text{ mAdc}$ , $I_B = -15 \text{ mAdc}$ ) ( $I_C = -500 \text{ mAdc}$ , $I_B = -50 \text{ mAdc}$ )	$V_{BE(sat)}$	-0.75	-0.95	Vdc
		-	-1.3	

**SMALL-SIGNAL CHARACTERISTICS**

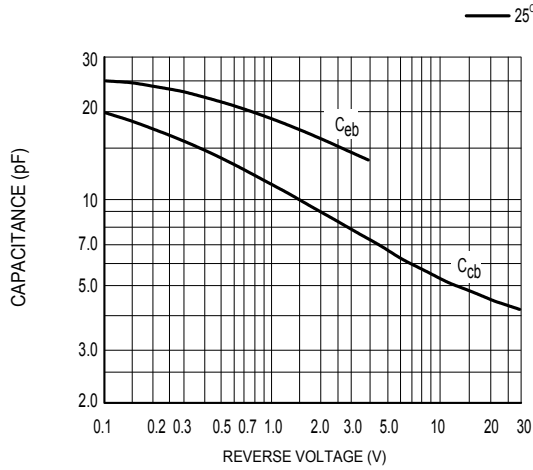
Current-Gain-Bandwidth Product ( $I_C = -20 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )	$f_T$	200	-	MHz
Output Capacitance ( $V_{CB} = -10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{cb}$	-	8.5	pF
Input Capacitance ( $V_{EB} = -0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{eb}$	-	30	pF
Input Impedance ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{ie}$	1.5	15	kohms
Voltage Feedback Ratio ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{re}$	0.1	8.0	$\times 10^{-4}$
Small-Signal Current Gain ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	60	500	-
Output Admittance ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{oe}$	1.0	100	$\mu\text{mhos}$

**SWITCHING CHARACTERISTICS**

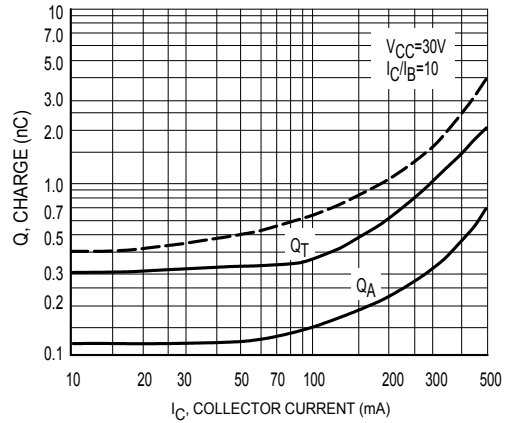
Delay Time	$(V_{CC} = -30 \text{ Vdc}$ , $V_{EB} = -2.0 \text{ Vdc}$ , $I_C = -150 \text{ mAdc}$ , $I_{B1} = -15 \text{ mAdc}$ )	$t_d$	-	15	ns
Rise Time		$t_r$	-	20	
Storage Time	$(V_{CC} = -30 \text{ Vdc}$ , $I_C = -150 \text{ mAdc}$ , $I_{B1} = I_{B2} = -15 \text{ mAdc}$ )	$t_s$	-	225	ns
Fall Time		$t_f$	-	30	

Note : Pulse Test: Pulse Width  $\leq 300 \text{ ms}$ , Duty Cycle  $\leq 2.0\%$

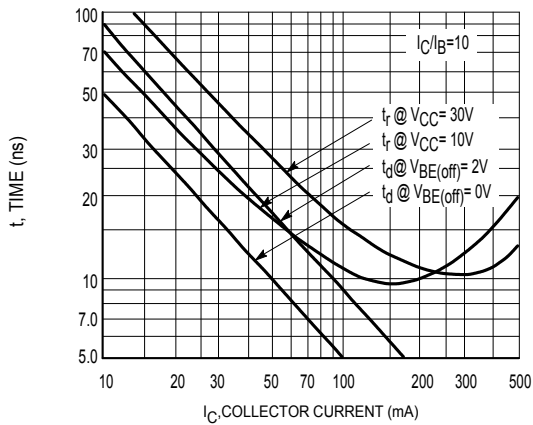
## RATING AND CHARACTERISTICS CURVES ( 2N4403 )



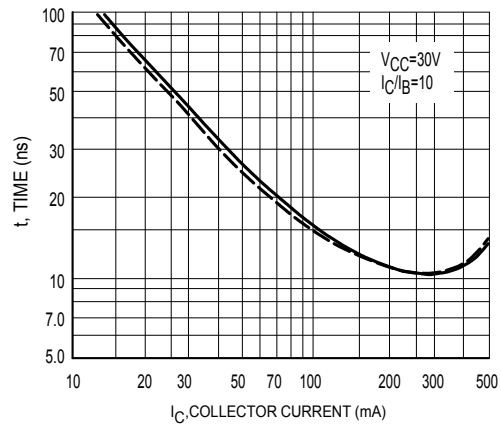
**Figure 1. Capacitances**



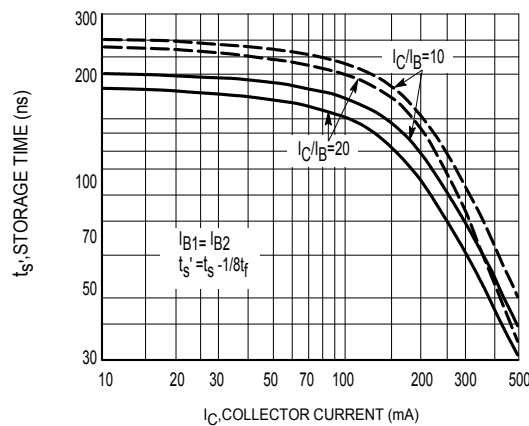
**Figure 2. Charge Data**



**Figure 3. Turn-On Time**



**Figure 4. Rise Times**



**Figure 5. Storage Time**

# RATING AND CHARACTERISTICS CURVES ( 2N4403 )

$V_{CE} = -10V_{dc}$ ,  $T_A = 25^{\circ}C$

Bandwidth = 1.0Hz

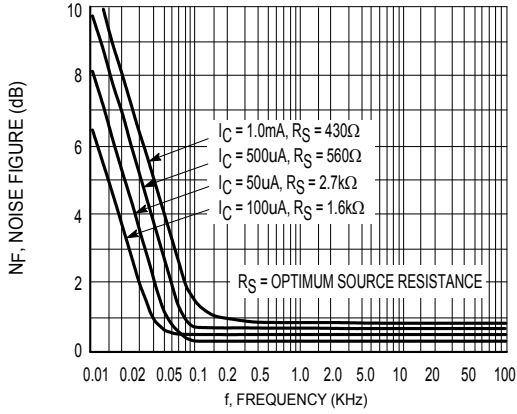


Figure 6. Frequency Effects

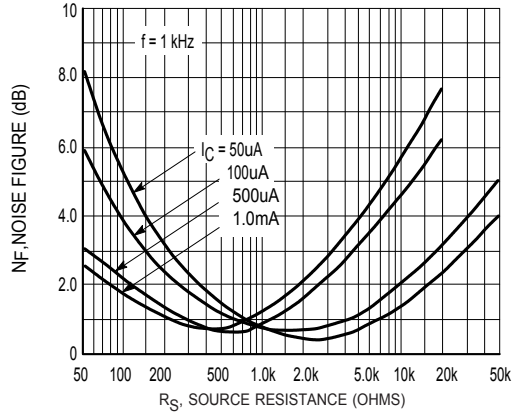


Figure 7. Source Resistance Effects

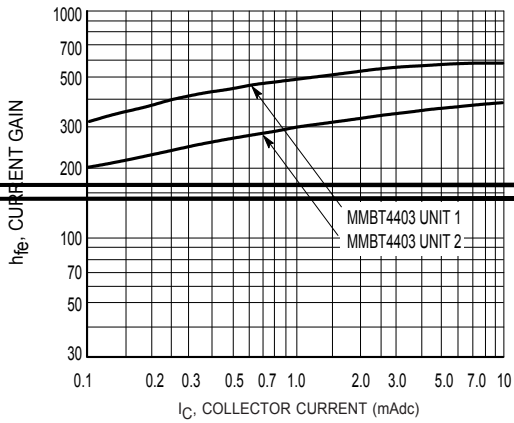


Figure 8. Current Gain

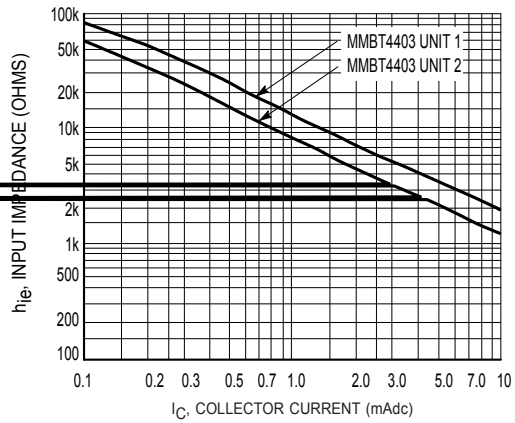


Figure 9. Input Impedance

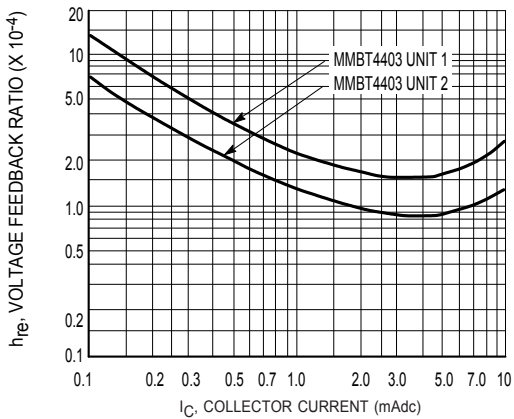


Figure 10. Voltage Feedback Ratio

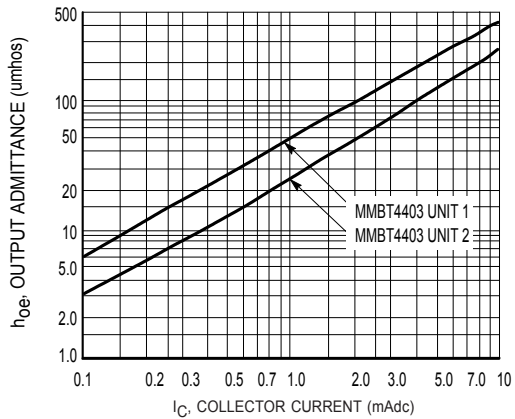


Figure 11. Temperature Coefficients

## RATING AND CHARACTERISTICS CURVES ( 2N4403 )

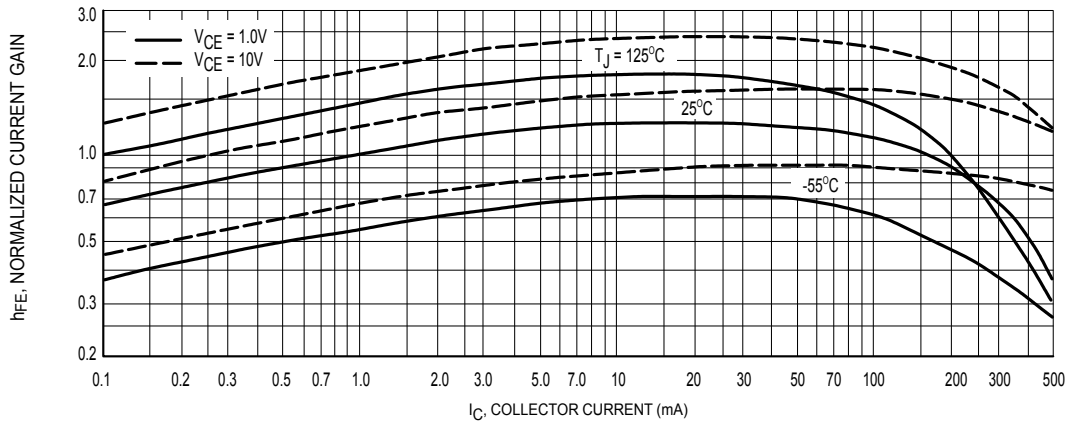


Figure 12. DC Current Gain

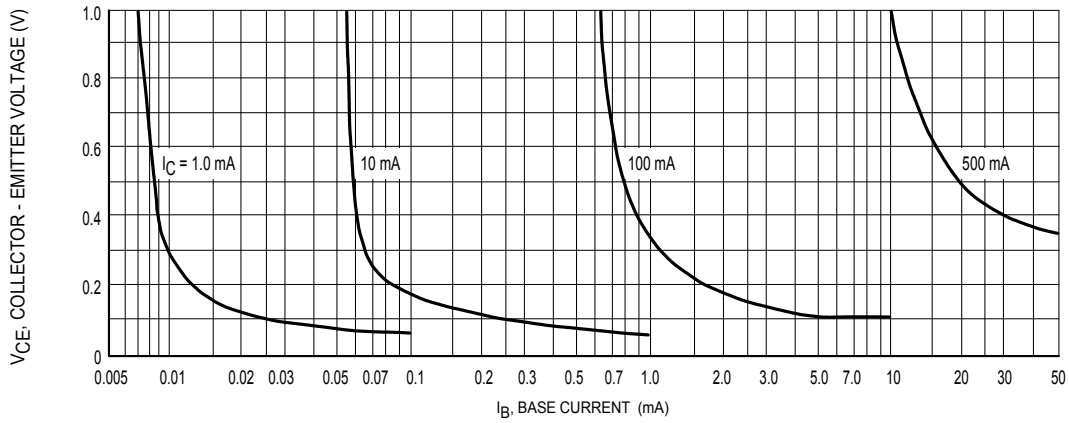


Figure 13. Collector Saturation Region

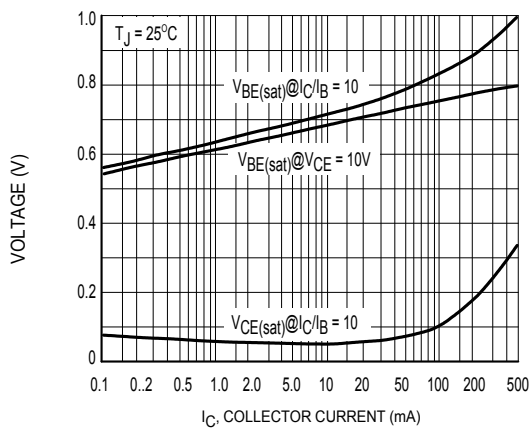


Figure 14. "ON" Voltages

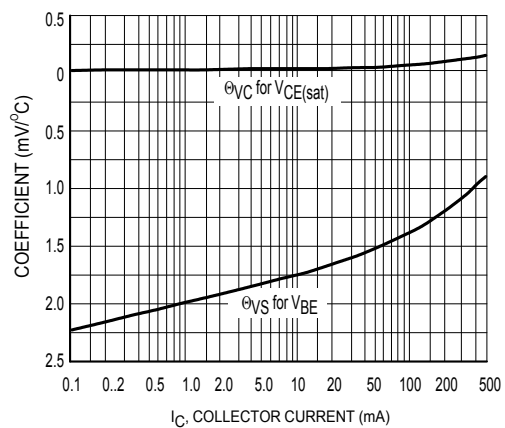


Figure 15. Temperature Coefficients

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